# N anom eter and sub-nanom eter thin oxide lm s at surfaces of late transition m etals

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If metal surfaces are exposed to su ciently oxygen-rich environments, oxides start to form. Important steps in this process are the dissociative adsorption of oxygen at the surface, the incorporation of 0 atoms into the surface, the formation of a thin oxidic overlayer and the growth of the once formed oxide lm. For the oxidation process of late transition metals (TM), recent experimental and theoretical studies provided a quite intriguing atom ic-scale insight: The formed initial oxidic overlayers are not merely few atom ic-layer thin versions of the known bulk oxides, but can exhibit structural and electronic properties that are quite distinct to the surfaces of both the corresponding bulk metals and bulk oxides. If such nanometer or even sub-nanometer surface oxide lm s are stabilized in applications, new functionalities not scalable from the known bulk materials could correspondingly arise. This can be particularly im portant for oxidation catalysis, where technologically relevant gas phase conditions are typically quite oxygen-rich. In such environments surface oxides may even form naturally in the induction period, and actuate then the reactive steady-state behavior that has traditionally been ascribed to the metal substrates. Corresponding aspects are reviewed by focusing on recent progress in the modeling and understanding of the oxidation behavior of late TM s, using particularly the late 4d series from Ru to Ag to discuss trends.

I. IN TRODUCTION

C on nem ent to nanoscale dim ensions and the resulting quantization of electrons gives rise to two-dimensional quantum Im s, one-dim ensional quantum wires, or zerodim ensional quantum dots. All three situations may exhibit properties and functionalities that make them different from the corresponding bulk material. In this respect, research on nanocatalysis is inspired by the expectation that due to such a reduced dimensionality of the active material new catalytic behavior can arise, which is not scalable from bulk-like properties.<sup>1</sup> A salient target of such investigations are nanom eter-size clusters of atom s, representing the three-dimensional con nement situation. W hile the potential of such clusters for catalytic applications is just being explored, it has already been recognized that they often exhibit the undesirable propensity to coarsen into larger aggregates on the support material. This problem could be less severe for the case of con nement in only one dimension, i.e. when striving for appealing properties of nanom eter or subnanom eter thin lm s. In fact, at the catalyst surface such lm s m ay even form autom atically during the induction period, as a consequence of the exposure to the operating conditions. A prominent example of this is oxidation catalysis, where the oxygen-rich environm ent m ight oxidize the sam ple. Recent experim ental and theoretical studies noted that particularly at late transition m etals (TM s) few or even one atom ic-layer thin, so-called surface oxide Im s are form ed, when these are held in a

realistic gas-phase environm ent under catalytic or alike (T;p)-conditions. The vertical con nem ent makes these lm s distinct to surfaces of both bulk m etals and bulk oxides, and their speci c properties can have bene cial, as well as detrim ental e ects on the desired functionality.

Appropriately tailoring and exploiting these functionalities requires an atom ic-scale characterization and understanding of the oxidation process, as well as of the resulting surface composition and stoichiom etry (under the steady-state reaction conditions). Although oxide form ation has been of technological and scienti c interest since long, such an understanding is, however, only just em erging, and the underlying m icroscopic processes are unfortunately still largely unclear for everything that goes beyond sub-m onolayer oxygen adsorbate phases on low-index single crystal surfaces. This holds in particular for the transition from an oxygen adsorbate layer to the surface oxide. A main reason behind this lack of understanding is that atom ic-scale investigations of TM surfaces on the verge of oxide form ation still pose a significant challenge for surface scientists: The need for rather high oxygen partial pressures (high compared to those possible in standard surface science experiments) and elevated tem peratures required to initiate the process, a low degree of order at the surface, and often complex, large unit-cell geom etries name but a few of the obstacles encountered. Since this often exceeds the analytical capabilities of one experim ental technique alone, multim ethod approaches (e.g. com bining scanning, di raction and spectroscopic m easurem ents) have becom e an im portant tool in this eld. In addition, rst-principles calculations, almost exclusively employing density-functional theory (DFT), have played a key role in this research area, in particular when suitably combined with concepts from thermodynamics or statistical mechanics. A lthough most of the arguments and understanding presented in this review are based on such calculations, I will not describe the methods them selves here, but refer to excellent monographs (see for example Refs. 2 and 3) for DFT itself, to Refs. 4 and 5 for applications to surfaces, and to Ref. 6 for the hybrid statistical mechanics methods.

Instead, this paper will focus on recent progress in the m odeling and understanding of oxide form ation of late TM s, using particularly the late 4d series from Ru to Ag to discuss trends. Section II will highlight aspects leading to the form ation of surface oxides, especially onsurface adsorption and accomm odation of oxygen in the sub-surface region. Key factors (also for the surface oxide stability itself) are the bulk-oxide heat of form ation, di usion energy barriers, elastic strain energies, and the nature of the surface-oxide { m etal interface. Som etim es the nano-or sub-nanom eter thickness of the form ed oxide Im is ruled by the therm odynam ic conditions, but often the thickness is determined by kinetics, e.g. by the diusion of metalor oxygen atoms (between interface and surface), or by the on-going oxidation reaction at the surface in a catalytic environment. Examples for both situations will be discussed in Section III, where we will also see that such thin oxide Im s can have a di erent structure to what is known from the stable bulk oxides. Setting these results into a \catalytic perspective", I will conclude in Section IV, for example that the catalytic activity of Ru in high-pressure oxidation reactions is likely due to nanom eter thin, but nevertheless bulk-like oxide patches, whereas for Pd and Ag the catalysis is more likely actuated by novel, surface-con ned sub-nanom eter thin oxidic structures.

# II. IN IT IALOXIDATION OF TRANSITION-METALSURFACES

#### A. Form ation of ad layers

O xide form ation at m etallic surfaces begins with the dissociation of the O<sub>2</sub> m olecule. This process is still not fully understood (see for example Ref. 7 and references therein), but for the present review we don't need to discuss this in detail. As the end product of the dissociation atom ic oxygen is chem isorbed at highly coordinated surface sites. Iw illmainly address the lowest energy surfaces of the late 4d TM s which have the hcp (0001) geom etry for Ru, and the fcc (111) geom etry for Rh, Pd, and Ag. For these systems the oxygen adatoms occupy threefold hollow sites which are sketched in Fig. 1. These two adsorbate positions, named hcp and fcc sites, di er only with respect to the second substrate layer: Below the hcp hollow site there is a second-layer atom, and below

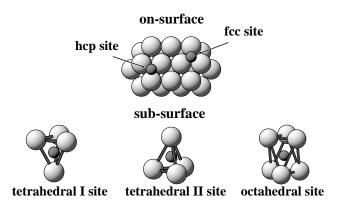


FIG. 1: Highly-coordinated adatom sites at a fcc(111) or hcp(0001) surface. The upper picture shows a top view of the surface, labeling the two threefold coordinated hollow sites. The lower row illustrates the local geometries of the three high-symmetry interstitial sites between the rst and second substrate layer. M etal atom s are depicted as light, large spheres, and oxygen atom s as dark, sm all spheres.

the fcc hollow site there is none. In other words, these sites represent positions atom swould occupy, if the crystal were continued in a hcp or a fcc stacking sequence. Interestingly, on the four 4d m aterials covered in this paper, oxygen prefers initially those threefold hollow sites that correspond to the stacking type of the substrate, i.e., the hcp hollow sites on Ru and the fcc hollow sites on Rh, Pd, and Ag. W ith increasing number of oxygen adatom s repulsive lateral interactions between the adsorbates lead to the form ation of ordered superstructures, typically with a (2 2) surface unit-cellat low coverages. Then, depending on the m aterial and whether higher coverage on-surface structures are formed at all, thism ay be followed by either (2 1) or (3 3)R 30 periodic overlayers, with oxygen atom s still occupying either hcp or fcc hollow sites.

The quantity ruling the adsorption-site preference and the form ation of ordered ad layers is the adatom binding energy:

$$E_{b}() = \frac{1}{N_{0}} \mathbb{E}_{0@ surf:} \mathbb{E}_{surf:} (N_{0} = 2) \mathbb{E}_{0_{2}}]:$$
 (1)

Here, N<sub>0</sub> is the total number of 0 atom s in the unit-cell at the considered coverage (m easured in m onolayers, M L, i.e. the fraction compared to the number of rst layer metal atom s). E<sub>00 surf</sub>; E<sub>surf</sub>; and E<sub>02</sub> are the total energies of the adsorbate system, of the corresponding clean surface before adsorption, and of the isolated oxygen m olecule. A positive binding energy E<sub>b</sub>() reects that the dissociative adsorption of 0<sub>2</sub> is exotherm ic. Equation (1) can be evaluated by DFT, and for big system s this is in fact the only approach that is currently feasible and predictive. O ne has to stress, how ever, that for oxygen at transition m etal surfaces such calculations are still dem anding. W ithout describing the technical challenges of perform ing such large-scale DFT studies, I

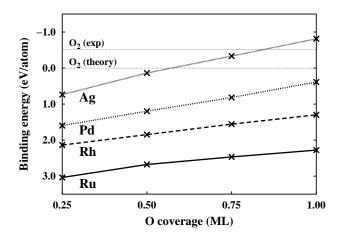


FIG. 2: Computed (DFT-GGA) binding energies  $E_b()$  for on-surface oxygen chem isorption into the most stable hollow sites of the basal surface of the late 4d TM s (Ru = hcp site, Rh/Pd/Ag = fcc site) and employing (2 2) surface unit-cells (the lines are only to guide the eye). The energies are given with respect to the theoretical O<sub>2</sub> binding energy, cf. eq. (1), while the upper horizontal dotted line indicates the zero-level, if the experimental O<sub>2</sub> binding energy were used (after Ref. 18).

only mention the basic problem : Though DFT is in principle exact, in practice it is not, because the exchangecorrelation (xc) functional is (and probably ever will be) only known approxim ately. Form any system s this is not a severe problem, but for the  $0_2$  m olecule even presentday gradient-corrected (GGA) functionals su er from a binding energy error of about 0.5 eV per O atom  $.^{8,9,10}$ Though som e error cancellation will occur in eq. (1), this 0, problem calls for caution when judging on the exo-or endotherm icity of oxygen adsorption or oxide form ation. Binding energy di erences between di erent adsorbate systems, for which the gas phase O<sub>2</sub> problem cancels out at least partially, appear fortunately often much less affected by the xc approxim ation. Still, caution is advisable, and if doubts exist, a regional xc correction, e.g., following the approach of Filippiet al.11, may be necessary.

E valuating eq. (1) is most useful for identifying adsorption sites, lateral interactions or the saturation coverage, and by such calculations the interplay between theory and experiment has indeed been most stimulating and synergetic in this eld. The atom ic scale characterization of higher coverage 0 adsorbate layers form s already an intriguing example for this. A lithough not really fully addressed and understood, it seems that the sticking coe cient for 0  $_2$  drops either dram atically after a certain threshold coverage at the surface is reached (Ru, Rh, Pd) or is very low from the beginning (Ag). Particularly the sharp drop after reaching a coverage of about 0.5M L at Ru (0001) and Rh (111) leads to an apparent uptake saturation, when employing low gas exposures as typical

for many early ultra-high vacuum (UHV) surface science studies. $^{12,13,14}$  DFT calculations predicted, how ever, that much higher coverages should still be possible<sup>15,16,17</sup>, and Fig. 2 shows such data for some selected adsorbate con gurations spanning the whole coverage range up to 1 M L<sup>18</sup>. A lthough the decreasing binding energies with coverage indicate repulsive interactions between the adsorbed 0 atoms, they are still clearly exotherm ic up to the full M L for Ru (and also for Rh). As for the 0/Ru case adsorption into other sites (e.g. below the surface) or other structures can be ruled out (see below), these results in ply that energetically the formation of denser overlayers is possible, well beyond the apparent saturation at 0:5M L. And in fact, by using more oxidizing gases that create higher partial pressures (e.g.  $NO_2$ ), orders of m agnitude higher  $O_2$  exposures (som etimes millions of Langmuirs) or the more novel, direct in-situ studies at elevated pressures such overlayers (and con gurations corresponding to even much higher 0 uptakes) are now routinely observed experimentally. One should stress, that on all four TM surfaces discussed in this paper, such experiments have opened a new door to study the oxidation beyond sub-m onolayer overlayers in a controlled fashion, signi cantly in proving the scienti c understanding over the last years.

Figure 2 also illustrates the mentioned  $O_2$ -molecule problem. Using in eq. (1) the experimental  $O_2$  total energy,  $E_{O_2}$ , instead of the theoretical one, would shift the energy zero to the upper dotted horizontal line. This is a too extrem e alternative though, because some xc error also exists in  $E_{O \ @ \ surf:}$  and  $E_{\ surf:}$ . Thus, the true energy zero is probably som where in between the two dotted lines. O bviously, in particular for silver the inaccuracy in the molecular binding requires special attention, even when only discussing the sign of the binding energy<sup>19</sup>. W hat is, how ever, unam biguously evident from Fig. 2 is that the oxygen-m etal bond strength decreases steadily from Ru to Ag, and this is in fact known qualitatively since long. The reason behind it is clearly visible in the projected density of states (DOS), which is de ned as<sup>4</sup>

N () = 
$$\int_{i=1}^{X^{i}} f_{i} f_{i} f_{i}$$
 (i): (2)

Here  $'_{i}$  are the Kohn-Sham orbitals, and is a properly chosen localized function, in the present case most suitably the Ru 4d and the O 2p atom ic orbitals within a sphere around given atom ic sites. A coording to the Anderson-Grim ley-Newnsmodelofchem isorption the interaction of the 0 2p level with the narrow 4d band of the TM surface gives rise to bonding states at the low er edge of the d-band and antibonding states at the upper edge of the d band. The corresponding peaks can be readily identied in Fig. 3, illustrating the projected DOS of a high coverage 0 adsorbate layer for the late 4d TM series. The Fermilevelm oves from the d-band center (for Ruit is already at a 70% lling) to about 3.5 eV above the top of the d band (for the noble m etal A q), and thus the antibonding oxygen {m etal states becom e progressively m ore

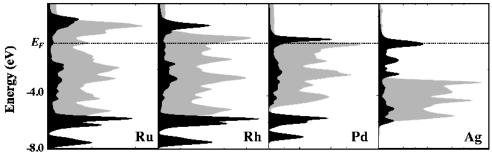




FIG. 3: Computed (DFT-GGA) projected density of states (PDOS), cf. eq. (2), of the clean basal surfaces of the late 4d TM s (gray shading), and of the O (1 1) adlayer (black shading). Shown are the N () contributions of the Ru 4d and O 2p states. The decrease of the oxygen PDOS band width (from left to right) and the increased lling of antibonding states (the higher-energy oxygen PDOS region) is clearly visible.

and m ore occupied.<sup>4,20,21</sup> As a consequence, the bond strength is weakened, explaining the steadily decreasing binding energies of Fig. 2. For the discussion below, it is nally worthwhile mentioning that despite these large variations of the binding energy with element (as well as with coverage), the oxygen-metal bond length does not change appreciably and stays always roughly at 2A.

# B. Oxygen accommodation below the top metal layer

It is often assumed that deposition of oxygen on metal surfaces gives initially rise to stable overlayers (either ordered or disordered). Apparently this is often correct, but there is no reason that it holds in general. In fact, oxygen atom sm ay wellgo below the surface, either staying in the near-surface region or dissolving into the bulk. Or, metal-oxide patches could form immediately. Experin entally, very little is unfortunately still known about this. For the basal surfaces of the late 4d transition m etals recent DFT-GGA calculations indicate that initially oxygen adatoms stay at the surface, and only when the coverage exceeds a certain value som e adatom s will go sub-surface.<sup>18</sup> They then remain preferentially close to the surface, i.e., they will not dissolve into the bulk .22,23 The interaction between these sub-surface oxygen atom s is attractive, and this situation m ay well already be called a surface oxide, or  $\stage I''$  of oxide form ation.

In principle, oxygen m ay occupy interstitial or substitutional sites in the crystal, but m ostly due to the high cohesive energy of the late TM s the latter are found to be energetically much less favorable.<sup>19</sup> Thus, they will not play a role in therm odynam ic equilibrium, or close to it, and we may focus our discussion on interstitial sites. D irectly below the topm ost m etal layer, i.e. in the immediate sub-surface region, there are three highsymmetry possibilities for such interstitial sites (cf. Fig. 1). N am ely, there is an octahedral site (henceforth called

octa) and a tetrahedral site (tetra-I) directly below the on-surface fcc and hcp site, respectively. And there is a second tetrahedral site (tetra-II) directly below a rst layer m etal atom . The m ain trends in the energetics of on-versus sub-surface oxygen are already discernible by comparing surface structures containing from one up to four 0 atoms in a model subset of (2 2) unit-cells. Of these up to four adatom s, consider that any one can be located either on- or below the surface in any of the high-symmetry sites displayed in Fig. 1. Despite the ostensible simplicity of this model subset, the number of possible combinations of on- and sub-surface oxygen atom s in various site and sym m etry con gurations is still. quite large, as exemplied in Fig. 4 by all con gurations where one out of a total of four oxygen atom s is located below the surface. Interestingly, from all these structural possibilities the combination of on-surface 0 in fcc sites and sub-surface 0 in tetra-I sites was in all four late 4d m etals found to be energetically either most stable or very close to the most stable geom etry.<sup>18,19,22,24,25</sup>

O coupation of sub-surface sites will com m ence at a certain total coverage c, when a structure with a non-zero fraction of the 0 atoms below the surface is energetically more favorable than the pure on-surface adsorption (corresponding to a zero fraction of oxygen atom s below the surface). Figure 5 sum m arizes the energetics within the described model subset at the basal surface, and we see that for all four late 4d TM s on-surface adsorption is initially more favorable than sub-surface incorporation. However, with increasing coverage this picture changes as the aforedescribed repulsive lateral interactions between the on-surface oxygen atom s progressively diminish the preference for adsorption into these sites. As can be deduced from Fig. 5 this threshold coverage , is beyond 1ML for Ru and Rh, i.e. oxygen incorporation will only start after completion of a full 0 (1 1) overlayer, in nice agreem ent with experim ental ndings.<sup>26,27</sup> C lose to = 1 M L the energy di erences are very small in the case of Rh though. Hence, a -

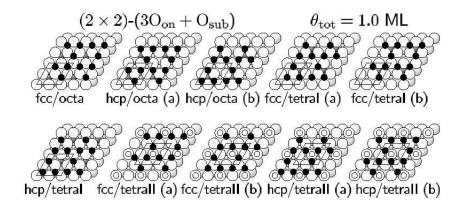


FIG. 4: Top view of all possible on-surface/sub-surface site com binations at a total coverage = 1 M L with one oxygen atom per (2 2) surface unit-cell located below the surface, i.e. corresponding to a fraction of 25% below the surface (see Fig. 1 for the explanation of the di erent sites). The metal atom s are drawn as big spheres (white for the surface layer, gray for second layer), and the oxygen atom s are drawn as small spheres (black for on-surface, gray for sub-surface). O xygen atom s in tetra-II sites below the rst layer metal atom s are invisible in this plot and are schem atically indicated by small white circles. Sym metry inequivalent occupation of the same kind of on- and sub-surface sites are denoted with (a) and (b), respectively.

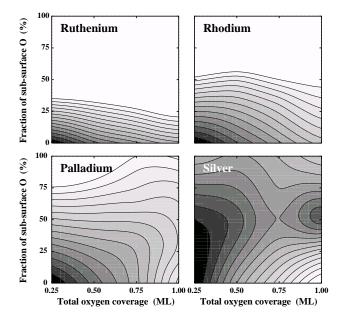


FIG. 5: A veraged binding energy  $E_b$  (using DFT-GGA and eq. (1)) as a function of the total O coverage of which a certain percentage is located below the basal surface (on-surface in fcc and sub-surface in tetra-I sites). The highest  $E_b$  are always found for the pure on-surface chem isorption phase at = 0.25 M L (chosen as zero reference, black area), with each contour line (lighter gray areas) at 0.1 eV steps towards less stable  $E_b$  (from R ef. 18).

nite concentration of sub-surface oxygen m ight already be present at total coverages even slightly below 1M L at elevated temperatures.<sup>24,28</sup> For Pd,  $_{\rm c}$  lies around 3/4M L, and for Ag sub-surface incorporation starts almost immediately (cf. Fig. 5).

This trend for sub-surface accomm odation of oxygen atom sat the late 4d TM s can be understood by looking at the sub-surface geom etries. In all relaxed structures the sub-surface oxygen-m etalbond lengths are slightly larger than 2A, i.e. they are sim ilar to the on-surface O {m etal distances. Comparing these bond lengths with the available geom etrical space inside a frozen m etal lattice, one nds them to be rather incom patible. For the unrelaxed tetra-I site of the late 4d m etals the bond length would range from 1.65 A (Ru) to 1.80 A (Ag). Thus, oxygen incorporation necessarily must go together with a substantial local expansion of the metal lattice. As shown by Todorova et al.<sup>18</sup> the bond strength of sub-surface oxygen atom s m ay therefore roughly be divided into a stabilizing contribution due to the chem ical binding and a destabilizing contribution from the lattice deform ation cost. Going from Ru to Ag the rst component should follow the same d-band-lling trend of the oxygen-m etal bond strength that was discussed in Section IIA for onsurface oxygen. And also the latter component follows this trend, i.e., it scales roughly as the bulk cohesive energy or the bulk modulus, which are largest for Ru and sm allest for Ag as noted in Fig. 6. The two contributions (O {m etal bond strength and m etal-lattice distortion energy) have opposite sign and apparently roughly com pensate each other, leading to a rather sim ilar energetic stability of sub-surface oxygen in all four elements.<sup>18</sup>

Due to the lattice-deform ation cost sub-surface oxygen turns out initially less favorable than on-surface adsorption, but with increasing coverage the repulsive lateral interactions for on-surface oxygen drive this preference down until eventually penetration of some oxygen adatom s becomes favorable. As the on-surface bond strength decreases from Ru to Ag, while the sub-surface bond strength stays roughly constant, this crossover will occur progressively earlier, i.e. c is large for Ru and

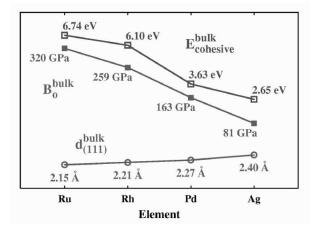


FIG.6: Trend of DFT-GGA computed bulk modulus, cohesive energy, and layer distance in (111) direction for the late 4d TM s.

### small for Ag.

If oxygen penetrates, the deform ation cost also rationalizes, why sub-surface incorporation was found to be m ore favorable com pared to bulk dissolution. A lthough the latter occurs of course always to some extent just on entropy grounds, there will at any rate be an enrichm ent of oxygen atoms in the easier to relax interstitial sites in the immediate near-surface fringe. And one could expect this deform ation argum ent to hold even more for sub-surface sites close to even low er coordinated atom s, i.e. interstitials in the vicinity of point defects, steps or dislocations. The latter are in fact frequently believed to be the nucleation centers for surface oxide form ation, and kinetic arguments like an easier 0 penetration are often put forward as explanation. Yet, we see that the therm odynam ic deform ation cost factor could also favor an initial oxygen accomm odation close to such sites.

# ${\tt C}$ . Oxygen accumulation in the surface region and surface oxide form ation

Them odynam ically the bulk oxide will start to form at the oxygen coverage,  $_{\rm c}^{\rm thd}$ , at which the average oxygen binding energy, cf. eq. (1), equals the oxide heat of form ation<sup>29</sup>. The word \coverage" is used here in a wider sense, i.e. meaning the total am ount of oxygen atoms in the near-surface region. Interestingly, the just discussed  $_{\rm c}$  for the initial incorporation of oxygen at sub-surface sites in the late 4d m etals does not only follow  $_{\rm c}^{\rm thd}$  in trend, but also in approxim ate value<sup>18</sup>. This suggests sub-surface oxygen as an interm ediate, or a precursor, for the form ation of the bulk oxide or other oxidic structures beyond on-surface adsorbate layers. Recent experimental studies seem to support this view, i.e., they indicate that thin oxidic structures, now mostly coined surface oxides, start to form roughly at coverages  $_{\rm c}^{-30,31,32,33,34}$ 

For the \true" bulk oxide a higher oxygen concentra-

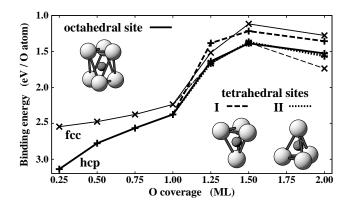


FIG. 7: B inding energies, calculated by DFT-GGA, for oxygen at Ru (0001). Coverages with 1ML correspond to pure on-surface adsorption (hcp or fcc site). For > 1ML an O (1 1) arrangement is always present at the surface, cf. Fig. 5, while the remaining O is located in either of the three interstitial sites between the rst and second substrate layer. From the six possible structures at each coverage, the three with on-surface O in hcp (fcc) sites are drawn with thicker (thinner) lines (from Ref. 22).

tion m ight be required, but for oxide nucleation and for the form ation of oxidic islands such increased oxygen content is only needed locally. In this respect it is remarkable that although for the on-surface adsorption at the late 4d TM basal surface the adatom -adatom interaction is repulsive (see the discussion of Fig. 2 above), an attractive interaction was found for sub-surface oxygen atoms in Ru (0001) and Rh  $(111)^{22,24}$ . This is illustrated in Fig. 7, which shows the course of the average binding energy ofO at Ru (0001) upon increasing the amount of oxygen atom s between the rst and second substrate layer up to 1 M L sub-surface coverage, i.e., 2 M L total coverage. A s discussed in the last section, for Ru (0001) oxygen penetration starts only after the full on-surface monolayer coverage is reached. Up to = 1M L the binding energy decreases steadily due to the repulsive lateral interactions. For even higher coverages, i.e. upon the ensuing

lling of sub-surface sites, the binding energy curve exhibits an in ection. This implies overall attractive interactions that favor an accumulation of sub-surface oxygen in dense two-dimensional islands with a local  $(1 \ 1)$ periodicity.<sup>22</sup>

W hile for Ru  $(0001)^{22}$  and Rh  $(111)^{24}$  the attractive interactions lead to dense oxygen islands with a local  $(1 \ 1)$  ordering below the surface, cf. Fig. 7, at Ag (111) it already becomes more favorable to incorporate oxygen rather between deeper layers, when a local sub-surface oxygen coverage of 1=4M L is exceeded.<sup>23</sup> Apparently, each metal is only able to sustain a certain amount of oxygen per layer, and the di erences between Ru and Ag are signi cant. W hereas Ru (0001) can accomm odate a full oxygen m onolayer on the surface plus a full oxygen m onolayer on and 25% below the top Ag layer.

W hat seem s to be a m ore general feature, how ever, is the 0-m etal-0 trilayer type structure, that results from the accumulation of sub-surface oxygen below the topm ost, oxygen-adsorbate covered m etal layer. This accumulation will eventually lead to the form ation of an ordered structure, which as already m entioned above, one could denote as a surface oxide, or \stage I" of oxide form ation. This is to distinguish it from sub-surface oxygen, which often conveysmore the notion of a random ly incorporated 0 species in the near-surface fringe. Although we expect from the deformation cost argument an enrichm ent of the latter com pared to bulk dissolved 0, one should stress that an experim ental identication of either (bulk or sub-surface 0) species will be very di cult: The concentration of bulk dissolved 0 is therm odynam ically quite low in the late 4d TM crystal lattices<sup>22,25</sup> and will thus only yield small signatures (which as a note aside does not m ean that the total am ount of dissolved 0 in the whole crystalmust be small though). And even though possibly enriched to a higher concentration, the signals from sub-surface 0 will also be small, since now only a sm all volum e of the crystal will contribute. In fact, subsurface oxygen has hitherto been quite elusive with only very few experim ental studies claim ing to have provided direct evidence for it. W hat is more frequent is that spectroscopic features that could not otherwise be explained have been interpreted as being due to a sub-surface oxygen species.

W ithin the deform ation cost picture, it appears in any case rather likely that (depending on the O exposure and kinetic barriers) a (lateral and vertical) aggregation of sub-surface oxygen will directly lead to ordered surface oxide structures. We will see below, that these structures are indeed oxide precursors, which may often have a som ewhat sim ilar stoichiom etry as the bulk oxides (e.g. RuO<sub>2</sub> and Ag<sub>2</sub>O for the two mentioned trilayer structures, respectively), but the geometries can di er signi cantly. Experimentally it may be sim ilarly involved, though not impossible, to identify such structures, because also an ensuing transition to other oxidic precursors or eventually the \true" bulk oxide ( Im ) may proceed fast.

#### D. Form ation of the bulk oxide

Continued accommodation of oxygen at the surface will eventually yield to the phase transition towards the \true" bulk oxide structure. For di erent materials this happens at di erent oxygen bad, and the pathway from the rst form ed surface oxide to the nalbulk oxide may well com prise other oxidic precursor structures. In general, one has to adm it that our atom ic-scale know ledge speci c to this step in oxide form ation is again very shallow. Particularly for the more noble TM s the low stability of the bulk oxides requires either very high oxygen pressures and/or rather low tem peratures for the experimental preparation. At the low er tem peratures the

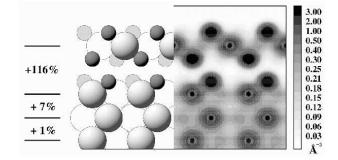


FIG.8: Side view of the detached  $\$ oating trilayer" of O at Ru(0001), corresponding to the most stable geometry with = 3M L.The left half of the gure shows the schematic geometry together with the relative layer expansions com pared to the bulk distance and the right half the calculated electron density. Ru = large spheres, O = sm all spheres, Ru atom s not lying in the shown plane are whitened (from Ref. 36).

grow th is largely a ected by kinetic limitations though, so that at Pd (111) at best sm allPdO clusters without apparent crystalline order were hitherto reported<sup>35</sup>, while at Ag (111) there exists literally no atom ic-scale know hedge on the oxidation process beyond the form ation of an ordered p(4 4) surface oxide (see below). This situation is far better for Ru (0001) and Rh (111), where it is at least know n that the oxidation process ends with the form ation of crystalline nutile-structured RuO<sub>2</sub> (110)<sup>31</sup> and corundum -structured Rh<sub>2</sub>O<sub>3</sub> (0001) Im s<sup>32</sup>, respectively.

This detailed know ledge of both initial state (the aforedescribed 0-Ru-0 trilayer) and nal state (the rutile structured RuO<sub>2</sub> (110) Im ) made it possible to elaborate for the rst time on an atom istic pathway for the structural phase transition towards the bulk oxide<sup>36</sup>: If the oxygen load at the Ru (0001) surface is increased beyond the 2ML coverage O-Ru-O trilayer, cf. Fig. 7, the surprising nding of the corresponding DFT-GGA study was that these additional oxygen atom swould also go preferentially between the rst and second substrate layer, i.e. where already one fulloxygen layer exists. The result is displayed in Fig. 8. It shows that a signi cant relaxation takes place such that the form ed O-Ru-O trilayer is essentially oating on an O/Ru adsorbate system. W ith the trilayer decoupled, increasing the oxygen load further then gives rise to two 0-Ru-0 trilayers and so forth. Still, this is not yet a know Ru-oxide structure, neither with respect to the energy, nor the geom etry.

As the trilayer on top has apparently only negligible in uence on the underlying metal, a continued exposure to oxygen is likely to produce sequentially more and more of these trilayers, which one after the other will become decoupled from the metal substrate. This way a bosely coupled stack of trilayers will successively be formed. C om paring the geometry of these trilayers with the one of a nutile (110) layer, it can be noticed that the former can be transformed into the latter by a simple accordionlike lateral expansion of the trilayer as explained in Fig. 9. With this expansion the self-contained trilayer un-

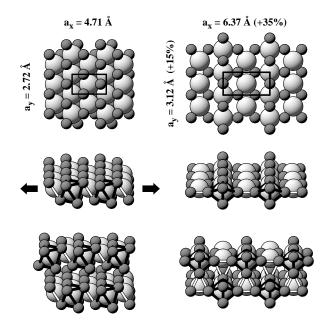


FIG.9: A tom ic geometries of the O-Ru-O trilayer shown in Fig. 8 (left-hand side) and of the nal rutile RuO  $_2$  (110) oxide structure (right-hand side). Top panel: top view, indicating the largely di erent sizes of the surface unit-cells. M iddle panel: perspective view . The bulk-like rutile structure is achieved by simply stretching the trilayer in direction of the arrows, keeping the length of the drawn 0-0 bonds (white and black lines) rigid. This way an alternative sequence of fully coordinated Ru atoms (inside the tilted O octahedra, black bonds) and coordinatively unsaturated (cus) Ru atom s (surrounded by only four 0 atom s, white bonds) is created. Bottom panel: coupling of two trilayers vs. that of rutile layers. W hereas the self-contained trilayers hardly bind, new bonds can be form ed in the RuO<sub>2</sub> (110) structure. The bridging 0 atom softhe fulloctahedra (black bonds) form the apex atom s of the new octahedra (white bonds) around the form er cus Ru atom s. Note, that the bonds' drawn do not refer to chem ical bonds, but are merely used to guide the eye (from Ref. 36).

folds into a more open geom etry, in which every second Ru atom is undercoordinated compared to the ideal sixfold oxygen surrounding both o ered in the trilayer and in bulk RuO<sub>2</sub>. It is precisely these coordinatively unsaturated (cus) m etal atom s that may eventually lead to a stabilization of the nutile structure for higher lm thicknesses, as they can provide extra inter-layer bonds that can not be form ed between the saturated trilayers. W hile for only one layer thick lm s the more compact trilayer o ers therefore a more favorable con guration, this preference was already found reversed at a two layer thickness, eventually inducing the transition to nutile through the accordion-like expansion.<sup>36</sup>

A dm ittedly, this idealized pathway for one speci c surface can barely be able to represent the com plex atom ic rearrangements and stoichiometry changes one can expect more generally during this oxidation step. Still, it contains at least one aspect that appears quite crucial: the e ect of strain. A salready pointed out before, oxygen incorporation will always lead to a substantial local expansion of the crystal lattice of late 4d TM s, and known bulk oxide structures of the latter are accordingly much m ore open compared to the close-packed bulk m etals. In the direction perpendicular to the surface, nothing opposes such an expansion and the corresponding vertical relaxations upon 0 incorporation can be quite substantial. Lateral relaxations, on the other hand, will con-

ict with the binding of the form ed oxidic fringe to the underlying metal lattice. In the formation of (surface) oxides, the system therefore has to nd an optimum energy compromise between elastic strain relaxation and good coupling to the underlying substrate. This may result in com m ensurable or incom m ensurable overlayers, and both types have already been observed experim entally on the late 4d basal surfaces.<sup>31,32,33,34</sup> In addition, strain m ay be easier relaxed at m ore open sites like steps, pointing again at the relevance of the latter for the oxidation process. Apart from the strain energy, another in uential factor is the therm odynam ic driving force to form an oxide. The latter will roughly scale with the bulk oxide heat of form ation, which steadily decreases from  $RuO_2$  to  $Ag_2O$ . The concom itant, lower stability of oxidic structures per se, together with easier to deform m etal lattices, m ight then render the coupling to the underlying substrate m ore im portant tow ards the m ore noble metals, i.e. the nature of the oxide-metal interface plays an increasing role. In this respect it is intriguing to notice that particularly at Pd (111) and Ag (111) pseudom orphic surface oxide structures have been reported, with a structure that seems particularly suited to maxim ize the interaction with the m etal lattice below .

## III. IM PLICATIONS FOR OXIDATION CATALYSIS

#### A. The role of the gas phase

A salient feature emerging from studies of the kind brie y sketched in the rst part of this review is that the initial oxidation of late 4d TM sproceeds via few atom iclayer thin oxidic structures, the electronic and geom etric structure of which may deviate signi cantly from their known bulk oxide counterparts. This makes these surface oxide Im s distinct to surfaces of both bulk m etals and bulk oxides, and one is led to wonder whether they exhibit speci c new properties that can be exploited for a desired functionality like catalysis. In this respect, one has to recognize, how ever, that in such applications (and m any experiments) the actual therm odynam ic variable is not the oxygen accomm odation at the surface, but the partial pressures and tem perature in the surrounding gas phase. Instead of looking at the change of the state of the surface as e.g. a function of increased exposure (or uptake) as done in the preceding sections, the relevant question to ask is then rather what happens to the TM

surface given certain environm ental conditions?

Exposed to an unlimited supply of gas phase particles characterized by the applied pressures and tem perature, the surface will adapt on time scales set by the kinetic limitations. A lready these time scales could be su ciently long to render corresponding m etastable states interesting for applications. In fact, the classic example is a slow thickening of oxide Im s due to lim itations in the di usion of oxygen atom s from the surface to the oxidem etal interface, or in the di usion of m etal atom s from the interface to the surface.<sup>37,38</sup> D irectly at the surface a similar bottleneck can be the penetration of oxygen, which m ight be signi cantly facilitated at steps and defects and thus adds to their relevance particularly for the formation of surface oxides also from a kinetic point of view. Still, although such kinetic barriers might slow the oxidation process down beyond noticeable time scales, in a pure oxygen gas phase the true therm odynam ic ground state will eventually be reached. With respect to oxide form ation this is often loosely equated with a completely oxidized sample, and it thus came as quite a surprise that for the more noble 4d TM sDFT-GGA indicates that there are in fact (T;p)-conditions, for which a nanom eterthin surface oxide represents the therm odynam ically stable phase. This means that in such environments a thin In is autom atically form ed at the oxidizing surface, the grow th of which is self-lim ited to the potentially particularly interesting nanom eter or sub-nanom eter width.

Reactive multi-component gas phases, as typical for e.g. catalysis, add another twist to this situation. In this case, we are dealing with an open system, in which the supply of reactant gases com es into contact with the solid surface, where a chem ical reaction produces a new substance that is then transported away. The average surface structure and com position is in this case entirely determ ined by the kinetics of the various underlying atom istic processes like adsorption, desorption, di usion or reaction. Still, for given tem perature and partial pressures of the reactants a steady-state situation m ay be reached (or even aspired for a stable catalyst perform ance), but this steady-state must not necessarily correspond to any therm odynam ic state. Particularly for oxidation reactions, the O-rich environment might for example constantly oxidize the catalyst surface, while the on-going reaction continuously consumes oxygen in such a way, that oxide formation never proceeds beyond a certain state. Sim ilar to the therm odynam ic situation described above, this could also lead to a self-lim ited thickness of the oxidized surface fringe.

# B. Stability of surface oxides in an oxygen environm ent

If we initially focus on the e ect of a pure oxygen gas phase, it is useful to rst resort to a therm odynam ic description. This allows to assess the various stages in the oxidation process when the surface is fully equilibrated with its environment, and thus provides a sound basis for an ensuing discussion on how kinetic limitations could affect the picture. Particularly interesting in the context of this review is in this respect whether the thin surface oxides are mere kinetic precursors to bulk oxide grow th or may actually represent a stable phase for certain gas phase conditions, as well as whether we can identify a trend over the late 4d TM series. For a surface in contact with a gasphase characterized by tem perature T and pressure  $p_{0_2}$ , a therm odynam ic description takes place in the grand-canonical, constant (T;p)-ensem ble and one needs to generalize eq. (1) to evaluate the G ibbs free energy of adsorption<sup>23,39,40</sup>

$$G(_{O}) = (3)$$

$$= \frac{1}{A} (G_{O@ surf:} G_{surf:} N_{O} O N_{M}) :$$

Here, A is the area of the surface unit-cell, and G<sub>0@ surf:</sub> and G<sub>surf:</sub> are the G ibbs free energies of the oxidized and clean surface, respectively. <sub>0</sub> and <sub>M</sub> are the chem i-calpotentials of oxygen and m etal atom s, and N<sub>0</sub> is the num ber of oxygen atom s contained in the oxidized surface structure for which G( $_0$ ) is computed. Finally, N<sub>M</sub> is the di erence in the num ber of m etal atom s between the reference clean surface and the oxidized surface structuralm odel.

In the di erence between the two G ibbs free energies, the contributions due to vibrational free energy, con gurational entropy and pV -term cancel to some extent, and for the oxidized late 4d TM surfaces discussed here replacing the G ibbs free energy di erence by the di erence of only the leading total energy term s appears to provide a reasonable approximation.<sup>41,42</sup> This simpli es eq. (3) to

G ( 
$$_{\circ}$$
 ) (4)  
 $\frac{1}{A}$  [N  $_{\circ}$  E  $_{b}$  (O @ surf:) + N  $_{\circ}$   $_{\circ}$  + N  $_{M}$  M ];

where  $E_b$  (0 @ surf:) is the average binding energy of oxygen in the oxidized surface, evaluated via eq. (1), and where the oxygen chemical potential is now m easured with respect to the total energy of an isolated O<sub>2</sub> m olecule as reference zero,  $_0 = _0 E_{O_2} = 2$ .

Eq. (4) has a rather intuitive structure: Forming the oxidized surface by accom odating N<sub>0</sub> oxygen atoms yields an energy gain of N<sub>0</sub> E<sub>b</sub> (O @ surf:), that is opposed by the cost of taking these O atoms out of a reservoir, hence N<sub>0</sub> <sub>0</sub>. The equivalent term N<sub>M</sub> <sub>M</sub> comes only into play for oxidized surfaces, where the total number of m etal atoms is di erent to the one of the reference clean m etal surface, and represents then the cost of transferring the corresponding number of m etal atom s to or from a reservoir with chemical potential M. For the m etal atoms, this reservoir is for oxidized surfaces offen conveniently chosen to be the m etal bulk, with which the surface is assumed to be in equilibrium.<sup>23,39,42</sup> The oxygen atom reservoir, on the other hand, is given by the

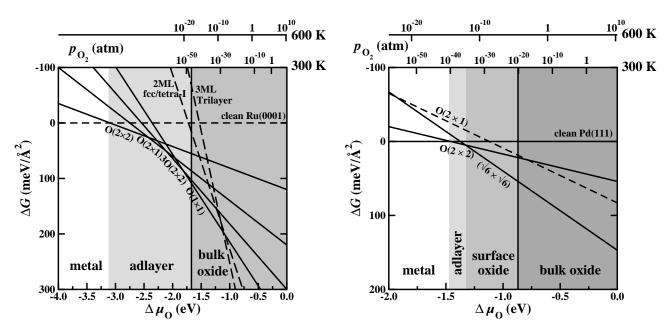


FIG. 10: Computed DFT-GGA G ibbs free energy of adsorption for several ordered on-surface adsorbate structures, surface oxides and the bulk oxide. The dependence on  $_{0}$  is also translated into pressure scales at T = 300 K and T = 600 K for clarity. In the bottom of the gure, the \m aterial type" which is stable in the corresponding range of oxygen chem ical potential is listed and indicated by the shaded regions. Left: Ru (0001). Compared are 0 (2 2), 0 (2 1), 30 (2 2) and 0 (1 1) adsorbate phases with 0 in hcp hollow sites, cf. Fig. 2, with the two 0 - Ru-O trilayer structures discussed in connection with Figs. 7 and 8. Right: Pd (111). Compared are 0 (2 2) and 0 (2 1) adsorbate phases with 0 in fcc sites, cf. Fig. 2, with the so-called \ (  $\overline{6}$   $\overline{6}$ )" surface oxide shown in Fig. 11 (the binding energies used to construct these graphs are taken from Refs. 33,36,40).

surrounding gas phase, allowing to relate o to tem perature T and pressure  $p_{0_2}$  via ideal gas laws.<sup>42</sup> For  $_{0}$  (T;p<sub>0,2</sub>) in the environment, the therm oa given dynam ically stable phase maxim izes  $G( _{0})$ , and eq. (4) can be used to compare structural models for possible oxidation states of the surface, e.g. oxygen adlayers with di erent coverage versus surface or bulk oxides. Since E<sub>b</sub> (O @ surf:) from eq. (1) enters into eq. (4), all the caveats about DFT calculations of the oxygen binding energy mentioned in the beginning hold here as well. This uncertainty is further aggravated by the additional approxim ation due to the neglected free energy contributions, and dictates utmost care in the interpretation of the obtained results.

W hen explicitly comparing a set of structures in the sketched atom istic therm odynam ics approach, surfaces with higher 0 content will become more favorable the more O-rich the environment. In the lim it of low oxygen pressures the clean surface will obviously be most stable ( 0 ! 1, cf. eq. (4)), but this will eventually change with increasing chem ical potential in the gas phase. Them ore oxygen is accomm odated in a structure, the steeper the slope of the corresponding G ( 0)  $_{0}$ . In the limiting case of the bulk oxcurve with ide with its in nite number of 0 atoms this will nally yield a vertical line at a value of the oxygen chem ical potential that equals the bulk oxide heat of form ation per O atom  $.^{40}$  For any higher value of  $_{0}$ , the bulk oxide

represents then the therm odynam ically stable phase.

This overall structure is nicely visible in Fig. 10, which com pares several of the above discussed oxidation stages at the Ru (0001) surface. W hile for  $_{\circ}$  < 3:1eV the clean surface is most stable, four di erent O adsorbate phases with 0 in hop sites and increasing coverages from 1/4M L up to 1M L become progressively more stable for  $_{\circ}$  < 1:7eV, buk m ore 0 -rich environm ents. A bove  $RuO_2$  represents the most stable phase. The stability range of this bulk oxide is therewith so large that it in fact covers all realistically attainable pressures for tem peratures below T 600K, as illustrated in Fig. 10. In particular, one also notices that the O-Ru-O trilayer structures discussed above as possible interm ediates before the bulk oxide form ation are never therm odynam ic phases, suggesting that at best they could only be stabilized by kinetic limitations in the ensuing phase transition to the bulk oxide.

A qualitatively similar picture has recently been reported for R h (111)<sup>32</sup>, where after adsorbate phases with O in fcc sites, bulk R h<sub>2</sub>O<sub>3</sub> becomes most stable at higher oxygen chemical potentials. Due to the already decreased heat of formation per O atom of R h<sub>2</sub>O<sub>3</sub> compared to R uO<sub>2</sub>, the stability range of the bulk oxide is smaller, but starts in contrast to the situation at R u (0001) nevertheless before higher coverage adsorbate phases corresponding to  $^{>}$  0.5M L could become favorable. This limit is only approximate though, since one should keep in mind

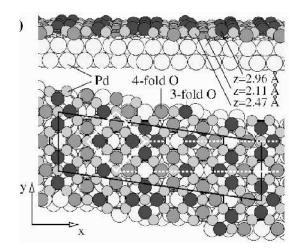


FIG.11: Top-and side view of the pseudo-commensurate, so-called  $\setminus (\begin{array}{c} 6 \end{array})$  surface oxide structure determined on Pd(111). The atom ic positions do not seem to resemble the bulk PdO arrangement, but exhibit roughly a 0-Pd-0 trilayer type structure (from Ref. 33).

that in such atom istic them odynam ics plots only the stability of a given set of structures is compared, and there could well be yet uncharacterized, higher coverage structures with a su ciently high average binding energy to show up as a new stable phase. Still, bulk oxide form ation appears at this surface therm odynam ically preferred already before a fullM L O (1 1) adsorption phase, which is consistent with the trend towards easier O accommodation from Ru to Ag discussed in the rst part of this review. A lthough a O-Rh-O trilayer structure equivalent to the one discussed for Ru (0001) above results sim ilarly as only a kinetic precursor in DFT-GGA, it is interesting to note that at Rh (111) this structure could recently be experimentally prepared and characterized close to step edges.<sup>32</sup>

Proceeding to Pd (111) one observes in most aspects a continuation of the identi ed trends. A sapparent in Fig. 10, the again reduced therm al stability of the PdO bulk oxide shows up by a further decreased stability range, which commences nevertheless already at an 0 chemical potential below the one required to stabilize higher <sup>></sup> 1=4M L.On the on-surface adsorbate coverages with other hand, there is also a qualitatively new feature, since now the experim entally observed, so-called  $\langle (6) \rangle$ 6)" pseudo-com m ensurate surface oxide structure displayed in Fig. 11 is not only a kinetic precursor, but represents the stable phase for an intermediate range of  $_{0}$ .<sup>33</sup> This is therefore similar to the reported ndings at Ag (111), of a p (4 4) surface oxide that is therm odynam ically stable over a wide range of 0 chem ical potentials, bounded on the one end by the stability range of a low coverage adsorbate phase and on the other end by the bwstability Aq<sub>2</sub>0 bulk oxide.<sup>23,39</sup> Both the  $\langle \overline{6} \rangle$ 6)" surface oxide on Pd (111) and the p (4 4) surface oxide on Ag(111) seem to have a highly complex, O-metal-O

trilayered atom ic structure that does not resemble the corresponding bulk oxides, cf. Fig.  $11^{29,32}$  Instead, these structures appear particularly suited to achieve a good coupling to the underlying substrate, and it is this extra contribution that enhances their stability over a wide (T;p)-range beyond the one of the known bulk oxides.

Summarizing the trend, we therefore see a changing role of thin surface oxide Im s in the oxidation process over the late 4d TM series. For Ru and Rh the present data suggests that such precursor structures to bulk oxide formation can only be stabilized by kinetic limitations. At the more noble metals Pd and Ag they instead represent a therm odynam ically stable phase over an increasing range of gas phase conditions. In corresponding oxygen environm ents, these nanom eter-thin Im swill eventually form on time scales set by possible kinetic limitations, but never grow thicker. Due to this nite thickness, the coupling at the oxide-m etal interface and an atom ic structure that can be quite di erent to the one of the known bulk oxides, onem ight suspect new properties that are distinct to those of surfaces of both bulk m etals and bulk oxides, and could thus be of potential interest for applications. For the speci c functionality in oxidation catalysis, one needs, how ever, also to assess the role played by the second reactant.

### C. \Constrained equilibrium "

A lthough the average surface structure and com position is in catalysis even under steady-state conditions determ ined by the kinetics of the on-going elem entary processes, it has been suggested that a therm odynam ic approach with certain constraints could still provide a rst insight into the e ect of the reactive environm ent on the state of the catalyst surface. 43,44 A straightforward generalization of the above described atom istic therm odynam ics concept to a multi-com ponent environm ent would be to account in eq. (4) for a corresponding number of reservoirs described by chem ical potentials i, where i denotes the di erent gas phase species. M odeling the catalyst surface in the reactive environm ent, each reactant is thus represented by a corresponding reservoir, with which the surface is in contact. However, in a full therm odynam ic description all reservoirs would also be mutually in equilibrium . Under catalytically interesting environm ental conditions, this yields directly the products as most stable environment, and is thus inadequate to treat the e ect of exposure to the reactant gas phase.

Since it is precisely the high free energy barrier for the direct gas phase reaction that requires the use of the catalyst in the rst place, it is appealing to instead consider the surface in contact with separate, independent reactant reservoirs. The surface would then be fully equilibrated with each reactant species, but the latter are not equilibrated with each other. A lthough neglecting the direct gas phase reaction is well justi ed, such a \constrained equilibrium " approach is still highly ap-

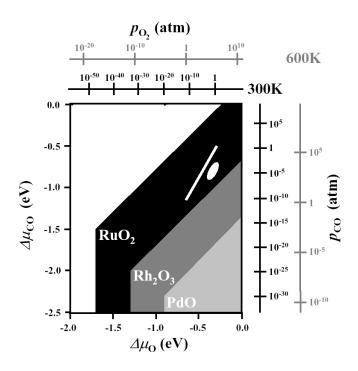


FIG.12: Stability regions of bulk oxides of the late 4d TM s in ( $_0$ ;  $_{CO}$ )-space, as computed with DFT-GGA.Additionally, pressure scales are drawn for T = 300K and T = 600K. The white line indicates environm ental conditions corresponding to  $p_{O_2} = p_{CO} = 1$  atm and 300K T 600K, and environments relevant for CO oxidation catalysis over these metals would correspond to the near vicinity of this line. M ore speci cally, the small white area indicates the (T;p)-conditions employed in a recent experimental study by Hendriksen, Bobanu and Frenken on Pd(100) (s. text)<sup>45</sup> (from R ef. 40).

proximate, as it e ectively also neglects the on-going catalytic product form ation at the surface itself, i.e. in other words exactly what one is in principle out to study. In this respect one should stress that the whole concept of a \constrained equilibrium " is not designed to yield precise answers to the m icroscopic state and reactivity of the catalyst surface. For that, the very dynam ic behavior m ust be m odeled by statistical mechanics, as will be illustrated below. Yet, with atom istic therm odynam ics the large scale behavior can be traced out rst, possibly identifying those (T;p\_i)-conditions where a more re ned treatment explicitly accounting for kinetic e ects is necessary.

How this works in practice is nicely illustrated by comparing the stability range of the bulk oxides of the late 4d TM series within the context of CO oxidation catalysis, i.e. in a gas phase form ed of oxygen and CO.<sup>40</sup> The progressively decreasing heats of form ation of the m ore noble m etal oxides already discussed in the last section are also clearly discernible in Fig. 12, which shows the oxide stability range as a function of the two chem ical potentials in the gas phase. At very low CO chem ical potential, the situation in a pure O<sub>2</sub> surrounding is recov-

ered, and the stability range of RuO<sub>2</sub> and PdO coincides with the corresponding bulk oxide shaded regions in Fig. 10. W ith increasing CO content in the gas phase, this picture changes and the stability range gets eventually reduced due to CO -induced decom position. A Ithough uncertainties in the modeling of this decomposition translate presently into rather large error bars in the respective diagonal lim its in Fig.  $12_{I}^{40}$  a clear trend still em erges: Only the stability range of bulk RuO<sub>2</sub> extends well into environm ental conditions representative of technological CO oxidation catalysis, roughly indicated in Fig. 12 as a white line. For Rh on the other hand the stability range of its oxide has already decreased signi cantly. Even if the real system was in a situation close to therm odynam ic equilibrium, either m etal or bulk oxide could prevail under am bient conditions, depending on whether the exact partial pressures and tem peratures in the gas phase correspond to a situation above or below the stability line (which is at present in possible to assess due to the large uncertainty in the calculated position of this line). The bulk oxides of Pd and of Ag are nally already so unstable that they are unlikely to play a role in CO oxidation catalysis. The stability of A q20 in fact being so low, that it does not even show up anym ore within the chem ical potential range plotted in Fig. 12.

It is, how ever, in portant to realize that already quite thin oxide Ims at the surface would be su cient to induce a changed catalytic functionality. In this respect, just considering the stability of bulk oxides as representatives of thick, bulk-like oxide overlayers is not enough. Particularly at the more noble metals, we discussed already the extended stability range of the few atom iclayer thin surface oxide structures in a pure  $O_2$  gas phase, which could similarly prevail in a reactive multicom ponent environm ent. W hile the results of Fig. 12 indicate that thick, bulk-like P dO and A g2O overlayers will hardly play a role in CO oxidation catalysis, the picture could be quite di erent for the nanom eter thin surface oxide structures. Fig. 13 exemplies this with corresponding results for the case of a Pd (100) surface in constrained equilibrium with an  $O_2$  and CO environment.<sup>46</sup> Sim ilar to the aforediscussed situation at Pd (111), oxidation proceeds also at Pd (100) via a trilayer-structured 0-Pd-O surface oxide lm<sup>35</sup>, that was recently identied as essentially a strained and rum pled layer of PdO (101) on top of the Pd (100) substrate<sup>47</sup>. A though the (101) orientation is not a low-energy surface of bulk PdO,48 it gets stabilized in the commensurate (5 5)R 27° arrangement of the thin oxide Im due to a strong coupling to the underlying metal substrate. In line with our previous discussion one would then expect an extended stability range com pared to bulk PdO, that was indeed subsequently found both theoretically and experin entally for a pure  $O_2$  gas phase.<sup>49</sup> The atom istic therm odynam ics results sum marized in Fig. 13 suggest furtherm ore that this would indeed hold equally for Pd (100) in an  $O_2$  and CO surrounding. Comparing the stability of a large set of on-surface (co)adsorption, surface oxide

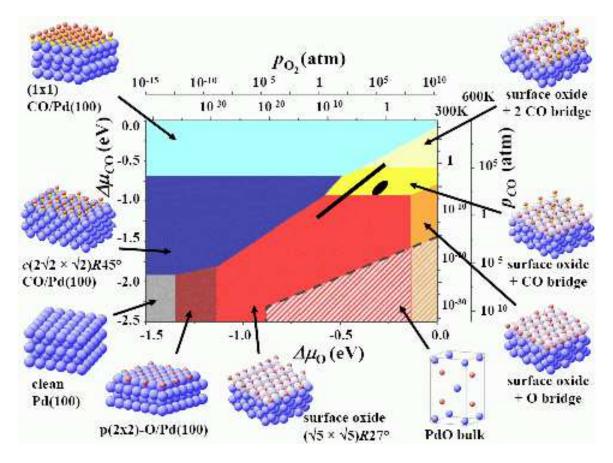


FIG.13: DFT-GGA surface phase diagram of stable surface structures at a Pd (100) surface in \constrained equilibrium " with an  $O_2$  and CO environment. The stability range of bulk PdO is the same as the one shown in Fig. 12. Phases involving the (55+5)R27 surface oxide exhibit a largely increased stability range, that now comprises gas phase conditions representative of technological CO oxidation catalysis ( $p_{O_2} = p_{CO} = 1$  atm and 300K T 600K, marked by the black line as in Fig. 12) (from Ref. 46).

and bulk oxide structures in constrained equilibrium with the reactive environm  $ent^{46}$ , several phases involving the  $(\overline{5}, \overline{5})R27$  surface oxide are found to be most stable over a wide range of (T;  $p_{0_2}$ ;  $p_{C0}$ )-conditions that largely exceed the small stability range of bulk PdO.

The range extends in fact so much that it even just comprises the gas phase conditions typical for technological CO oxidation, i.e. partial pressures of the order of 1 atm and tem peratures around 300-600K.Sim ilar conditions were e.g. also chosen in a recent in-situ reactor scanning tunneling m icroscopy (STM) experiment of CO oxidation at Pd (100) by Hendriksen, Bobaru and Frenken<sup>45</sup>, cf. Figs. 12 and 13. W ith increasing  $O_2 CO$ partial pressure ratio, the authors observed substantial changes in the surface morphology, which they assigned to the form ation of a thin oxidic overlayer<sup>45</sup>. Inspecting Fig. 13 it is tempting to identify this overlayer as the already characterized (5 5)R 27 surface oxide, but this would be rushing beyond what can be safely concluded on the basis of the presently available DFT data: First, surface structures that are not yet explicitly com pared in the atom istic therm odynam ics approach could still change the surface phase diagram . Second, kinetic

e ects could signi cantly a ect the oxidation state of the surface. This is the case, when the on-going catalytic reaction consumes surface species faster than they can be replenished from the surrounding gas phase, thus yielding an average surface structure and composition that can be quite distinct to the predictions obtained within the constrained equilibrium concept. It could in particular be that a fast consumption of surface oxygen atom s reduces the stability range of the surface oxide well below the technologically interesting environm ental conditions (which are even in constrained equilibrium quite close to the transition to the CO -covered Pd (100) surface phases). At the moment, the only safe take-hom e message from the data presented in Fig. 13 is therefore that instead of the already, ruled-out thick bulk-like P d0 lm, the nanom eter thin (555)R27 surface oxide appears as a likely candidate to actuate the increased catalytic activity connected with the morphology changes reported by Hendriksen and coworkers.<sup>45</sup>

Still, the proxim ity of the technologically relevant highpressure gas phase conditions to the phase transition between surface oxide and CO-covered Pd (100) in Fig. 13 is intriguing and stimulates further speculations. Depend-

ing on the exact partial pressures and tem peratures, either the surface oxide or the Pd (100) m etal surface could prevail. Even oscillations between the two phases are conceivable as a consequence of uctuations, when operating under environm ental conditions very close to the stability limit. At nite temperatures, con gurational entropy may furtherm ore give rise to a complex phase coexistence at the surface,  $^{42,44}$  which would then go in the direction of what was in the in-situ reactor STM experim ent interpreted as a continuous consumption and reform ation of the surface oxide even under the employed stationary reaction conditions.<sup>45</sup> Instead of the one-time formation of a catalytically active oxide Im in the case ofRu, this would point at a much more dynam ic state of the Pd surface in the reactive CO oxidation environm ent: The catalytic activity could be intim ately connected to a reversible (local) form ation and reduction of the thin surface oxide, possibly even giving rise to spatio-tem poral pattern form ation phenom ena as often reported for CO oxidation at Pt-group m etals.<sup>45,50,51</sup> In such cases, also the dom ain boundaries between surface oxide and adlayers could be of particular in portance for the overall reactivity.

#### D. K inetically lim ited lm thickness

The constrained equilibrium description discussed up to now conveys the impression that a possible oxidation of the catalyst surface in the 0 -rich environments of oxidation catalysis would rather yield bulk-like thick oxide

In son Ru, but thin surface oxide structures on them ore noble 4d m etals. This re ects the decreasing heat of form ation of the bulk oxides over the late TM series, and seem s to suggest that it is prim arily at Pd and Ag where oxide form ation in the reactive environm ent could be selflim ited to nanom eter or sub-nanom eter thin overlayers. Particularly for the case of Ru, Fig. 12 shows that the gas phase conditions typical for technological CO oxidation catalysis fall deep inside the stability regime of the bulk oxide, indicating that therm odynam ically nothing should prevent a continued grow th of the once form ed oxide Im.

The form ation of crystalline, bulk-like RuO<sub>2</sub> (110) during high-pressure CO oxidation catalysis has indeed been observed experimentally at Ru (0001), but it is interesting to note that even after long operation times the lm thicknesses never exceeded about  $20 \text{ A}^{30,31,52}$ . Generally, one could interpret this nding as relecting kinetic lm – itations to a continued growth, presumably due to slow di usion of either O or Ru atoms through the formed lm .<sup>37,38</sup> W hile this could slow the thickening of the oxide overlayer down beyond hithertom easured time scales, it could also be that the kinetics of the on-going catalytic reaction a list the surface populations in such a way, that no further net di usion through the lm occurs and the nanom eter thin oxide overlayer represents in fact a kinetically limited steady-state in the given reactive envi-

FIG.14: Top view of the RuO<sub>2</sub> (110) oxide surface explaining the location of the two prom inent adsorption sites (coordinatively unsaturated, cus, and bridge, br). A loo shown are perspective views of the four steady-state adsorption phases present in Fig. 15 (Ru = light large spheres, O = darkm edium spheres, C = white sm all spheres).

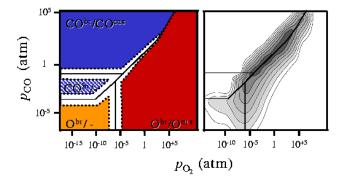


FIG. 15: Left panel: Steady state surface structures of  $RuO_2$  (110) in an  $O_2/CO$  environment obtained by rstprinciples kMC calculations at T = 600K. In all non-white areas, the average site occupation is dom inated (> 90%) by one species, and the site nom enclature indicates the species at the two prom inent adsorption sites o ered by the surface: br = bridge sites, cus = coordinatively unsaturated sites, cf. Fig. 14. Right panel: M ap of the corresponding catalytic CO oxidation activity m easured as so-called turn-over frequencies (TOFs), i.e.  $CO_2$  conversion per cm<sup>2</sup> and second: W hite areas have a TOF <  $10^{11}$  cm<sup>2</sup> s<sup>1</sup>, and each increasing gray level represents one order of m agnitude higher activity. The highest catalytic activity (black region,  $TOF > 10^{17}$  cm<sup>-2</sup> s<sup>-1</sup>) is narrow ly concentrated around the phase coexistence region, in which 0 and C0 compete for both br and cus sites (from Ref. 53).

ronm ent. This would e.g. be the case, if the oxidation reactions at the surface consum e adsorbed oxygen atom s at such a pace that on average 0 penetration into the lm occurs not more frequently than the lling of surface sites with oxygen from inside the lm.

To explore this in more detail one needs to go beyond the constrained equilibrium description and explicitly take kinetic e ects into account in the theoretical modeling. This can for example be achieved via kinetic M onte C arbo (kM C) simulations, which can essentially be viewed as coarse-grained molecular dynam ics simula-

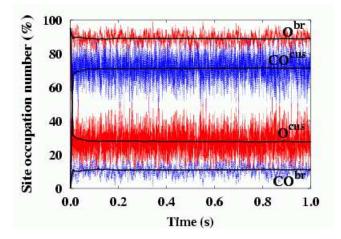


FIG.16: Time evolution of the site occupation by O and CO of the two prominent adsorption sites at the RuO<sub>2</sub> (110) m odel catalyst surface shown in Fig. 14. The temperature and pressure conditions chosen (T = 600K,  $p_{CO} = 20 \text{ atm}$ ,  $p_{O_2} = 1 \text{ atm}$ ) correspond to optimum catalytic perform ance, cf. Fig. 15. Under these conditions kinetics builds up a steady-state surface population in which O and CO compete for either site type at the surface, as re ected by the strong uctuations in the site occupations (from Ref. 53).

tions, following the time evolution of the system on the basis of the rates of all individual elementary processes occurring in the system .<sup>6,54,55</sup> Evaluating the statistical interplay between thism an ifold of atom ic-scale processes, kM C simulations can easily cover su ciently long time scales to arrive at proper averages of quantities like surface populations, even if the system is not in equilibrium, but only in a steady-state as typical for catalysis. Such a modeling was recently performed for the CO oxidation over RuO<sub>2</sub> (110), using DFT-GGA based rates for 26 elem entary surface processes including adsorption, desorption, di usion and reaction events.<sup>53</sup> O fparticular interest for the lm thickness issue is the occupation of surface sites with 0 atoms in catalytically relevant gas environments. In this respect, the RuO<sub>2</sub> (110) surface offers two prom inent adsorption sites, commonly denoted as bridge (br) and coordinatively unsaturated (cus) sites as explained in Fig. 14.42

Figure 15 shows the obtained steady-state average surface populations at T = 600 K as a function of the gasphase partial pressures, together with the sinultaneously computed turnover frequencies (TOF, in units of form ed CO<sub>2</sub> per cm<sup>2</sup> per second). The latter result from evaluating the average occurrence of the reaction events over long time periods as a measure of the catalytic activity, and are intriguingly peaked around a narrow range of gas phase conditions. Contrary to the situation at most other partial pressures, the site occupation at br and cus sites is then not dom inated by one species, i.e. either 0 or CO (or vacant). Instead, the kinetics builds up a surface population in which O and CO compete for either site type at the surface. This competition is in fact

nicely relected by the huge uctuations in the surface populations with time apparent in Fig. 16. The dynam ics at the surface in this \active state" is furtherm ore extrem ely fast, and the average tim e adsorbed 0 atom s stay in brorcus sites before desorbing or being reacted away is only of the order of fraction of milliseconds. Remarkably, it is particularly the concentration of 0 at the surface that turns out signi cantly lower than predicted within the constrained equilibrium approach<sup>43,44</sup>. Even at the bridge sites, where 0 atom s bind very strongly<sup>42</sup>, the O occupation is only 90% and not 100% as in the normally stable surface term ination. This is quite surprising, and indicates already how e ectively the on-going reaction consumes surface 0 species. It could therefore well be that the surface kinetics indeed lim its a continued grow th of the form ed oxide Im under this optimum catalytic perform ance.

### E. Surface oxidation and Sabatier principle

The partial pressures and tem peratures leading to this high activity state of the RuO<sub>2</sub> (110) surface in the calculations, and even the absolute TOF values under these conditions, agree extremely well with detailed experim ental studies m easuring the steady-state activity in the tem perature range from 300-600K and both at highpressures and in UHV<sup>56,57,58</sup>. This statem ent com prises already the emerging consensus that this Ru oxide also forms at the surface of Ru model catalysts in highpressure environm ents52,53, i.e. the high activity that was originally ascribed to the Ru substrate was in fact due to  $RuO_2^{56,57}$ . With this understanding a puzzle is nally resolved that had bothered surface scientists for quite a while: For a long time the high CO oxidation reactivity of supported Ru catalysts<sup>56</sup>, as well as of Ru (0001) single crystals<sup>57</sup> at high-pressures stood in sharp contrast to exceedingly low turnover rates observed under UHV conditions<sup>59</sup>, thus representing a nice example of a socalled \pressure gap" system  $^{60}$ .

Looking at the computed binding energies of oxygen at Ru (0001) shown in Fig. 2 the low catalytic activity of this surface appears in fact quite plausible. A coording to the early Sabatier principle<sup>61</sup> high activity would in general rather be expected for interm ediate bond strengths at the surface (stable enough to form, but weak enough to yield the nalproduct). In this respect the computed medium binding energies at e.g. Rh (111) and Pd (111) in Fig. 2 conform much better with the widespread use of these metals in catalytic car converters, whereas the oxygen bonding at R u (0001) seem s sim ply too strong. The correspondingly som enow enigm atic high catalytic activity of Ru (0001) at am bient pressures only becam e com prehensible when experim ental studies reported the form ation of bulk-like RuO<sub>2</sub> (110) In s at the surface in such reactive environments $^{30,31}$ . The subsequently established $^{62}$ and above described high activity of this oxide surface then not only explained the pressure gap di erence (Ru

m etal in UHV = low activity,  $RuO_2$  at high-pressures = high activity), but also reconciled this system with the Sabatier principle: The  $RuO_2$  (110) surface indeed features oxygen species that are bound with interm ediate bond strength comparable to the one of O at Rh(111) and Pd(111).<sup>42,58</sup>

An equivalent, though reverse explanation has also been suggested for the most noble of the late 4d m etals.<sup>63,64</sup> A coording to Fig. 2 oxygen binds to A g (111) only very weakly, which in view of the Sabatier principle is again di cult to combine with the known importance of Ag as catalyst for several oxidation reactions. How ever, the bond strength of oxygen in the p (4 4) surface oxide is substantially higher and would therefore well fall. into the more favorable medium binding energy range.64 If the surface oxide instead of Agm etalwas the actually active surface in the high-pressure oxidation catalysis, the Sabatier principle would nally be reconciled with the complete trend of oxygen binding over the late 4d series apparent in Fig. 2: Both the too strong O binding on Ru and the too weak O binding on Ag is alleviated by the form ation of oxides, which exhibit a similarly interm ediate bond strength as oxygen at Rh or Pd.

It thus alm ost appears as if the interaction of oxygen with TM catalysts would serve to \tune" the O-m etal bond strength for optimum reactivity through an appropriate amount of surface oxidation. Since the therm all stability of bulk  $Ag_2O$  is already too low and in line with our preceding extended stability discussion, this oxidation can at Ag at best correspond to the formation of a thin surface oxide though. Yet, compared to the surface oxides at Pd, even the latter is probably not stable enough to play an active role in CO oxidation. This can be di erent in the less reducing environments of partial oxidation reactions, consistent with the predominant use of Ag catalysts for ethylene epoxidation or form aldehyde synthesis<sup>61</sup>.

These examples underline therefore already nicely the potential relevance of surface oxidation in the reactive surroundings of oxidation catalysis. In all cases discussed so far, this had a bene ciale ect on the overall catalytic perform ance, but detrimental e ects due to the form ation of an inactive oxide lm are of course equally well conceivable. Such a catalyst deactivation through oxidation has e.g. been frequently suspected in the experimental literature concerning Rh surfaces.<sup>65,66,67</sup> In other cases, the catalytic activity of oxide and m etal surface might be comparable, so that surface oxidation would likely remain unnoticed unless explicitly looked for by experimental techniques sensitive to the atom ic-scale.

# IV. CONCLUSION

N ovel experimental and theoretical approaches addressing the e ect of realistic environments on surface structure and composition have signicantly increased the atom ic-scale understanding of the oxide formation

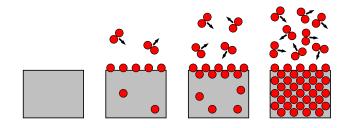


FIG.17: Cartoon sideviews illustrating the e ect of an increasingly oxygen-rich atm osphere on a late TM m etal surface. W hereas the clean surface prevails in perfect vacuum (left), nite  $O_2$  pressures in the environment rst lead to oxygen adsorption phases. A part from some bulk dissolved oxygen, the lower deform ation cost will at increasing pressures lead to a preferential accommodation of oxygen in the near-surface fringe. This surface oxide structures are the salient consequence, before eventually thickening of the oxide lm and form ation of an ordered bulk compound set in. A therm odynam ic or kinetic stabilization of the nanom eter thin surface oxide could lead to novel functionalities, di erent from both bulk m etal or bulk oxide surfaces.

process of late transition m etals over the last years. Som e identi ed key features have been reviewed for the late 4d sequence from Ru to Ag, and are summarized schematically again in Fig. 17: A progressively more O -rich gas phase leads rst to on-surface adsorption, followed by 0 penetration into the surface at increasing 0 accomm odation. The incorporation takes place after the form ation of dense oxygen overlayers in the case of Ru, but already at low er on-surface coverages tow ards the m ore noble m etals. This results from the opposing trends in decreasing 0-m etalbond strength and decreasing deform ation cost of the metal lattice, the latter being a consequence of the substantial local expansion necessarily connected to O incorporation into the close-packed TM lattices. The deform ation cost is also responsible for an enrichm ent of oxygen in the easier to relax immediate surface fringe, eventually inducing the formation of thin oxidic structures at the surface. A lthough som e bulk dissolution will always occur on entropy grounds, there is thus primarily a propensity to form few atom ic-layer thin surface oxides, which mostly goes hand in hand with substantial structural changes. The resulting geometry is then not only characterized by an optimum binding within the more open compound structure, but can also be largely affected by the coupling to the underlying m etal substrate (i.e. the nature of the oxide-m etal interface) and residual strain. As consequence, com plex atom ic arrangem ents not resembling surfaces of bulk oxides or bulk metals have been reported for this step in the oxidation process. Only after continued oxygen accomm odation, the thickening oxide Im will eventually switch to a bulk oxide structure, and the continued Im grow th will then be more and more limited by the slow diusion of 0 and/or m etal atom s between surface and interface.

A most intriguing aspect of this surface oxidation is

that it proceeds via the few atom ic-layer thin surface oxide structures. This thickness can be ruled by kinetics, but at Pd and Ag it even seems that there are therm odynam ic conditions for which the surface oxides represent the most stable phase. In corresponding environm ents such Im s are form ed autom atically, but the growth is self-lim ited to the potentially particularly interesting nanom eter or sub-nanom eter width. If stabilized in applications, the often quite distinct geometries of these lms already suggest that new properties and functionalities m ight em erge that are not scalable from the known bulk materials. At present, very little to nothing is known about these properties, and one should recall that not even the corresponding bulk oxides of the late 4d TM s have hitherto received a lot of attention in atom ic-scale studies. This opens up a wide new eld for investigations of this new \m aterial class" and its functionalities in various applications.

W ith respect to oxidation catalysis, oxide  $\ln s m$  ay even form as a natural consequence of the reactive environment, and since maybe hitherto unnoticed, they might then actuate some of the catalytic behavior that has traditionally been ascribed to the metal substrates. In this respect, the decreasing heat of form ation leads to a clear trend for the bulk oxides: A bulk-like RuO<sub>2</sub> Im can even sustain the reducing environments of high-pressure total oxidation reactions, whereas the feeble Ag<sub>2</sub>O will hardly prevail. This is, how ever, not enough to exclude the relevance of oxidized structures for oxidation catalysis over Pd and Ag catalysts. A leo due to the coupling to the underlying substrate, the thin surface oxides exhibit a much extended stability range, and it seems at the moment at least feasible that for exam ple CO oxidation over

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Pd is actuated by them , or their constant consumption and reform ation. The present data suggest a similar role for surface-con ned oxidic structures at Aq, but only in less reducing environments e.g. typical for partial oxidation. This would then also o er an intuitive explanation for the often reported high catalytic activity of noble m etals for such reactions. Together with the form ation of highly active, nanom eter thin RuO<sub>2</sub> Im s at the surface of Rum odel catalysts, this underlines the potential in portance of surface oxidation in the reactive environments of oxidation catalysis over late TM s. Although often not yet fully conclusive, already the reviewed new insights into the oxidation behavior help sometimes to reconcile the data with more general concepts like the Sabatier principle. Much more often, however, they lead to the falldown of \established" rules and preconceptions, which is a prospect that makes working in this eld exciting and all the worthwhile.

#### A cknow ledgm ents

I gratefully acknowledge the valuable contributions and help from my (form er) colleagues working on metal oxidation in the Theory Department of the Fritz-Haber-Institut: Jorg Behler, Veronica Ganduglia-Pirovano, Wei-Xue Li, Angelos Michaelides, Jutta Rogal, Cathy Stamp and Mira Todorova. Particular thanks go to Matthias Sche er for his continued support and for the insightful discussions on the intriguing facets of surface oxidation and catalysis.

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